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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/816,923	03/23/2001	Manfred Engelhardt	GR 98 P 2661	6120

7590 09/19/2002

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[REDACTED] EXAMINER

WILLIAMS, ALEXANDER O

[REDACTED] ART UNIT [REDACTED] PAPER NUMBER

2826

DATE MAILED: 09/19/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	09/816,923	ENGELHARDT, MANFRED
	Examiner Alexander O Williams	Art Unit 2826

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) Responsive to communication(s) filed on 12 August 2002.
- 2a) This action is FINAL. 2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1-11 is/are pending in the application.
- 4a) Of the above claim(s) 7-11 is/are withdrawn from consideration.
- 5) Claim(s) _____ is/are allowed.
- 6) Claim(s) 1-6 is/are rejected.
- 7) Claim(s) _____ is/are objected to.
- 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) The proposed drawing correction filed on _____ is: a) approved b) disapproved by the Examiner.
 If approved, corrected drawings are required in reply to this Office action.
- 12) The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

- 13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) All b) Some * c) None of:
 1.) Certified copies of the priority documents have been received.
 2.) Certified copies of the priority documents have been received in Application No. _____.
 3.) Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
 * See the attached detailed Office action for a list of the certified copies not received.
- 14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
 a) The translation of the foreign language provisional application has been received.
- 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

- 1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) Paper No(s). _____.
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 5) Notice of Informal Patent Application (PTO-152)
 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 7.9. 6) Other: _____

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Serial Number: 09/816923 Attorney's Docket #: GR98P2661P
Filing Date: 3/23/2001; claimed foreign priority to 9/23/98

Applicant: Engelhardt

Examiner: Alexander Williams

Applicant's election of Group I (claims 1 to 6) in Paper # 13, filed 8/12/02, has been acknowledged.

This application contains claims 7 to 11 drawn to an invention non-elected without traverse in Paper No. 13.

Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in the file.

The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

The disclosure is objected to because of the following informalities: The related application information should be updated.

Appropriate correction is required.

Claims 1 to 6 are rejected under 35 U.S.C. § 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 1, it is unclear and confusing to what is meant by "a second conductive structure disposed in said contact hole and **conductively connected to said first conductive structure.**" If the second conductive structure disposed in said contact hole is conductively connected to said first conductive structure, then the drawing and the invention must have an electrically connection from the second conductive structure

to the first conductive structure in the contact hole. Is this shown in the drawing of this is the case? It appears that the drawing only show this connection if the second diffusion barrier layer is an electrically conductive layer. If this is the case, why is it called a diffusion barrier layer? Please correct or explain this electrical connection.

Any of claims 1 to 6 not specifically addressed above are rejected as being dependent on one or more of the claims which have been specifically objected to above.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. § 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains.

Patentability shall not be negated by the manner in which the invention was made.

Claims 1 to 6, **insofar as they can be understood**, are rejected under 35 U.S.C. § 102(e) as being anticipated by Inohara et al. (U.S. Patent # 5,966,634).

For example, in claim 1, Inohara et al. (figures 1 to 27) specifically figure 21 show a integrated circuit configuration, comprising: an insulating layer **705**; a first conductive structure **720** embedded in said insulating layer; a diffusion barrier layer **725** and a second insulating layer **730** disposed above said first conductive structure and being formed with a contact hole **755** reaching as far as said first conductive structure and having side walls **765**; a second conductive structure (within the contact hole, not shown but inherit) disposed in said contact hole and conductively connected to said first conductive structure; and spacers formed on said side walls of said contact hole above said diffusion barrier layer, said spacers acting as a barrier to diffusion of a material from said first conductive structure into said second insulating layer and reaching as far as a surface of said diffusion barrier layer.

Claims 1 to 6, **insofar as they can be understood**, are rejected under 35 U.S.C. § 102(b) as being anticipated by Mu et al. (U.S. Patent # 5,612,254).

For example, in claim 1, Mu et al. (figures 1 to 13) specifically figure 9 show a integrated circuit configuration, comprising: an insulating layer **22**; a first conductive structure **41** embedded in said insulating layer; a diffusion barrier layer **23** and a second insulating layer **50** disposed above said first conductive structure and being formed with a contact hole reaching as far as said first conductive structure and having side walls **60**; a second conductive structure **61** disposed in said contact hole and conductively connected to said first conductive structure; and spacers formed on said side walls of said contact hole above said diffusion barrier layer, said spacers acting as a barrier to diffusion of a material from said first conductive structure into said second insulating layer and reaching as far as a surface of said diffusion barrier layer.

Claims 1 to 6, **insofar as they can be understood**, are rejected under 35 U.S.C. § 102(e) as being anticipated by Nguyen et al. (European Patent Application # 0892428 A2)

For example, in claim 1, Nguyen et al. (figures 1 to 18) specifically figure 18 show a integrated circuit configuration, comprising: an insulating layer **166**; a first conductive structure **188** embedded in said insulating layer; a diffusion barrier layer **190** and a second insulating layer **192** disposed above said first conductive structure and being

formed with a contact hole 206 reaching as far as said first conductive structure and having side walls 202,214; a second conductive structure 200 disposed in said contact hole and conductively connected to said first conductive structure; and spacers formed on said side walls of said contact hole above said diffusion barrier layer, said spacers acting as a barrier to diffusion of a material from said first conductive structure into said second insulating layer and reaching as far as a surface of said diffusion barrier layer.

The listed references are cited as of interest to this application, but not used at this time.

Field of Search	Date
U.S. Class and subclass: 257/758,700,701,704,741,751,750,753,774,773,759,760, 762-765,767	9/16/02
Other Documentation: foreign patents and literature in 257/758,700,701,704,741,751,750,753,774,773,759,760, 762-765,767	9/16/02
Electronic data base(s): U.S. Patents EAST	9/16/02

Papers related to this application may be submitted to Technology Center 2800 by facsimile transmission. Papers should be faxed to Technology Center 2800 via the Technology Center 2800 Fax center located in Crystal Plaza 4-5B15. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Technology Center 2800 Fax Center number is (703) 308-7722 or 24. Only Papers related to Technology Center 2800 APPLICATIONS SHOULD BE FAXED to the GROUP 2800 FAX CENTER.

Any inquiry concerning this communication or any earlier communication from the examiner should be directed to ***Examiner Alexander Williams*** whose telephone number is (703) 308-4863.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center 2800 receptionist** whose telephone number is **(703) 308-0956**.

9/16/02



Primary Examiner
Alexander O. Williams